TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM6P36FE

Power Management Switches

• 1.5-V drive

Low ON-resistance: $R_{on} = 3.60 \Omega \text{ (max) (@V}_{GS} = -1.5 \text{ V)}$

 $R_{OR} = 2.70 \Omega (max) (@V_{GS} = -1.8 \text{ V})$ $R_{OR} = 1.60 \Omega (max) (@V_{GS} = -2.8 \text{ V})$ $R_{OR} = 1.31 \Omega (max) (@V_{GS} = -4.5 \text{ V})$

Absolute Maximum Ratings (Ta = 25 °C) (Common to the Q1, Q2)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	-20	V	
Gate-source voltage		V_{GSS}	±8	V	
Drain current	DC	I _D	-330	mA	
	Pulse	I _{DP}	-660		
Drain power dissipation		P _D (Note1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

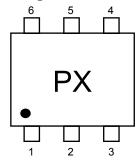
Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad: } 0.135 \text{ mm}^2 \times 6)$

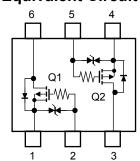
Unit: mm 1.6±0.05 1.2±0.05 6 ± 0.05 1.0 ± 0.05 5 1.Source1 2.Gate1 5 Gate2 6.Drain1 3.Drain2 ES₆ **JEDEC JEITA TOSHIBA** 2-2N1D

Weight: 3.0 mg (typ.)

Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (–1 mA for the SSM6P36FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

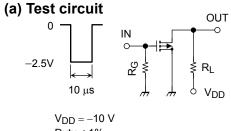
Take this into consideration when using the device.

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Character	ristics	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain-source breakdown voltage	V _{(BR)DSS}	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$		-20			V	
Diaiii-source breakdowii voltage		V _{(BR)DSX}	$I_D = -1 \text{ mA}, V_{GS} = 8 \text{ V}$		-12			
Drain cutoff current		I _{DSS}	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$		_		-10	μА
Gate leakage currer	nt	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$		_		±1	μА
Gate threshold volta	age	V _{th}	$V_{DS} = -3 \text{ V}, I_D = -1 \text{ mA}$		-0.3	_	-1.0	٧
Forward transfer ad	mittance	Y _{fs}	$V_{DS} = -3 \text{ V}, I_D = -100 \text{mA}$ ((Note2)	190	_	_	mS
Drain-source ON-resistance	R _{DS} (ON)	$I_D = -100$ mA, $V_{GS} = -4.5$ V (1	Note2)	_	0.95	1.31	Ω	
		$I_D = -80 \text{mA}, V_{GS} = -2.8 \text{ V}$ (1)	Note2)	_	1.22	1.60		
		$I_D = -40 \text{mA}, V_{GS} = -1.8 \text{ V}$ (1)	Note2)	_	1.80	2.70		
		$I_D = -30 \text{mA}, V_{GS} = -1.5 \text{ V}$ (1)	Note2)	_	2.23	3.60		
Input capacitance		C _{iss}			_	43	_	
Output capacitance		C _{oss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	10.3	_	pF	
Reverse transfer ca	pacitance	C _{rss}			_	6.1	_	
Total Gate Charge		Q_g			_	1.2	_	
Gate-Source Charge Gate-Drain Charge		Q_{gs}	V_{DS} = -10 V, I_{DS} = -330mA V_{GS} = -4 V	_	0.85	_	nC	
		Q_{gd}		_	0.35	_		
Switching time	Turn-on time	t _{on}	V _{DD} = -10 V, I _D = -100mA		_	90	_	
	Turn-off time	t _{off}	$V_{GS} = 0$ to -2.5 V, $R_G = 50\Omega$		_	200	_	ns
Drain-source forward voltage		V _{DSF}	$I_D = 330 \text{mA}, V_{GS} = 0 \text{ V}$ (N	Note2)	_	0.88	1.2	V

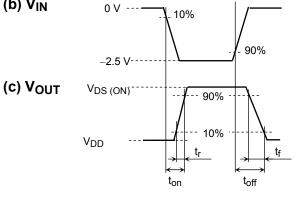
Note2: Pulse test

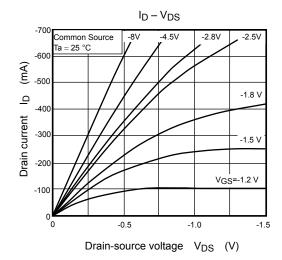
Switching Time Test Circuit

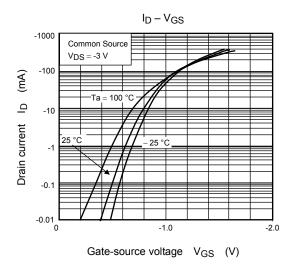


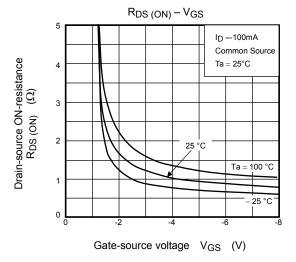
 $Duty \leq 1\%$ $V_{IN}\text{: }t_{r}\text{, }t_{f}<5\text{ ns}$ $(Z_{out} = 50 \Omega)$ Common Source $Ta = 25^{\circ}C$

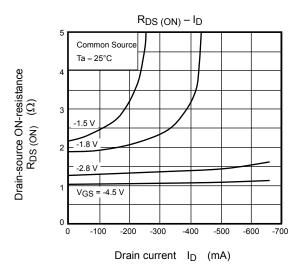
(b) V_{IN}

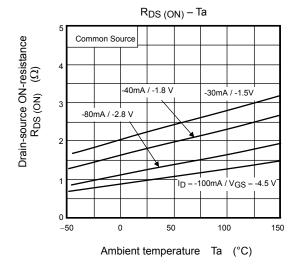


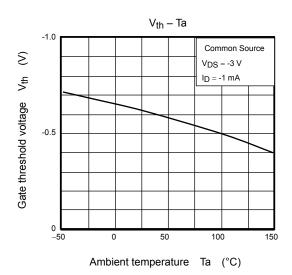


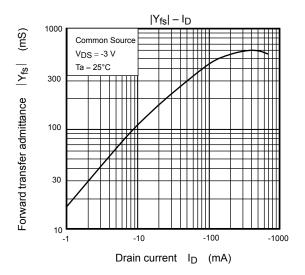


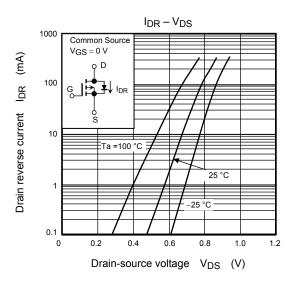


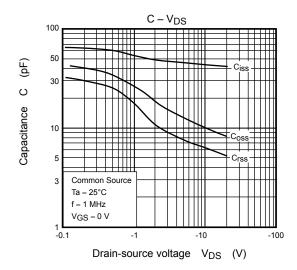


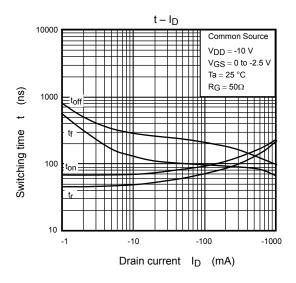


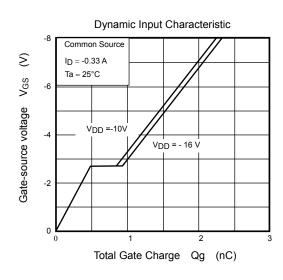


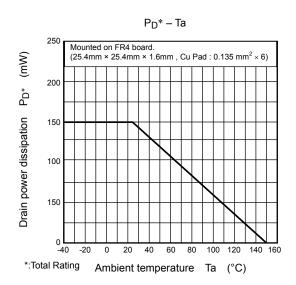












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